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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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2SK3147(L), 2SK3147(S)

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1072-0300 Rev.3.00 Aug 17, 2009

Features

- Low on-resistance $R_{DS} = 0.1 \Omega \text{ typ.}$
- High speed switching
- 4 V gate drive device can be driven from 5 V source

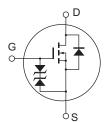
Outline

RENESAS Package code: PRSS0004ZD-B (Package name: DPAK(L)-(2))



RENESAS Package code: PRSS0004ZD-C (Package name: DPAK(S))





- 1. Gate
- 2. Drain
- Source
 Drain

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	100	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	5	A
Drain peak current	I _{D(pulse)} Note1	20	A
Body-drain diode reverse drain current	I _{DR}	5	A
Avalanche current	I _{AP} Note3	5	A
Avalanche energy	E _{AR} Note3	2.5	mJ
Channel dissipation	Pch Note2	20	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1 %

- 2. Value at Tc = 25°C
- 3. Value at Tch = 25°C, Rg \geq 50 Ω

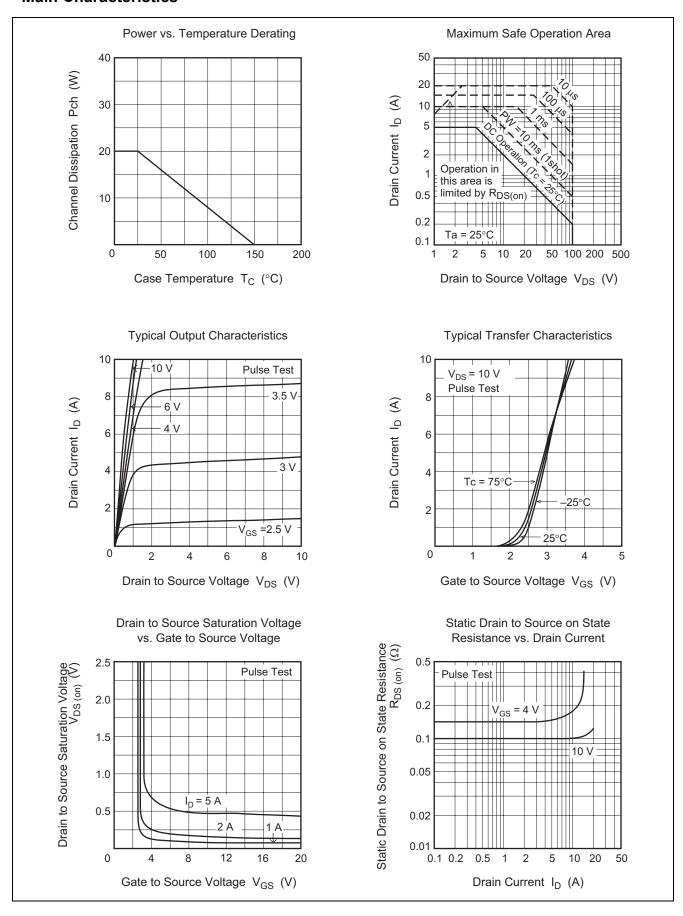
Electrical Characteristics

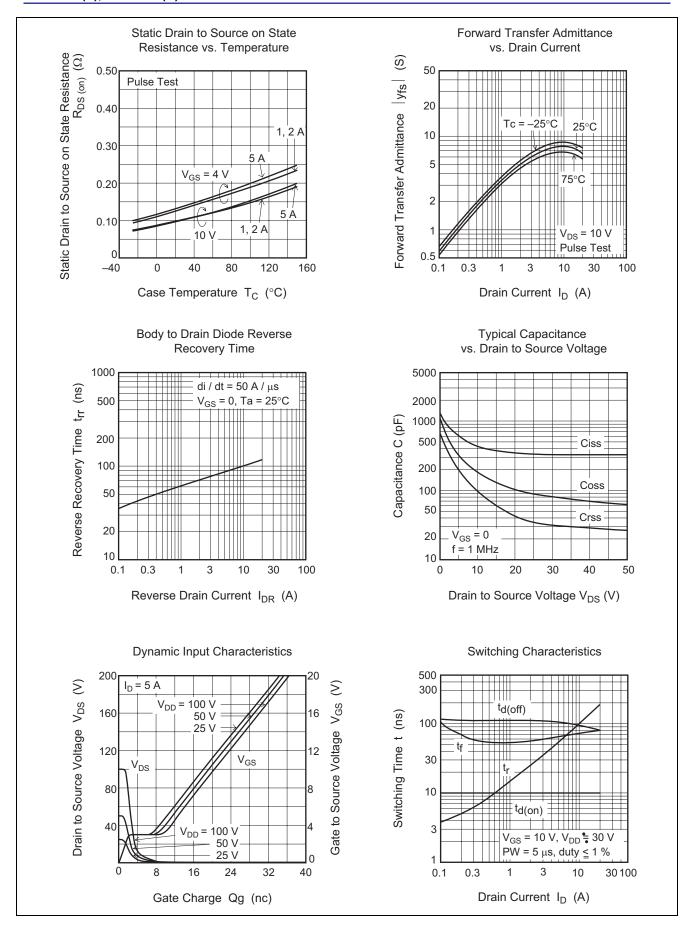
 $(Ta = 25^{\circ}C)$

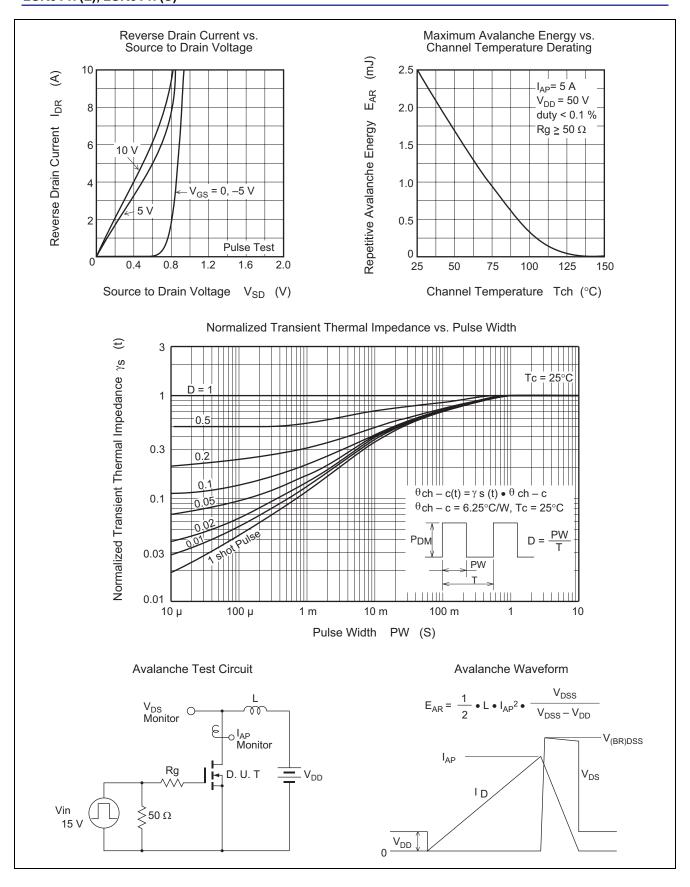
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	100	_	_	V	I _D = 10 mA, V _{GS} = 0
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	10	μΑ	V _{DS} = 100 V, V _{GS} = 0
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.5	V	I _D = 1 mA, V _{DS} = 10 V
Static drain to source on state	R _{DS(on)}	_	0.1	0.13	Ω	$I_D = 3 A, V_{GS} = 10 V^{Note4}$
resistance	R _{DS(on)}	_	0.13	0.17	Ω	$I_D = 3 A, V_{GS} = 4 V^{Note4}$
Forward transfer admittance	y _{fs}	3.5	6	_	S	$I_D = 3 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	420	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	185	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	100	_	pF	
Turn-on delay time	$t_{d(on)}$	_	10	_	ns	$I_D = 3 A, V_{GS} = 10V,$
Rise time	t _r	_	35	_	ns	$R_L = 10 \Omega$
Turn-off delay time	$t_{\text{d(off)}}$	_	110	_	ns	
Fall time	t _f	_	60	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.85	_	V	I _F = 5 A, V _{GS} = 0
Body-drain diode reverse recovery	t _{rr}	_	85	_	ns	I _F = 5 A, V _{GS} = 0
time						$di_F/dt = 50 A/ \mu s$

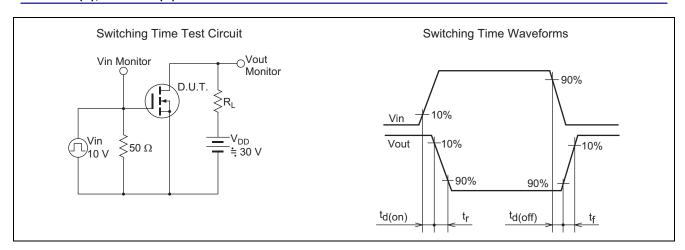
Note: 4. Pulse test

Main Characteristics

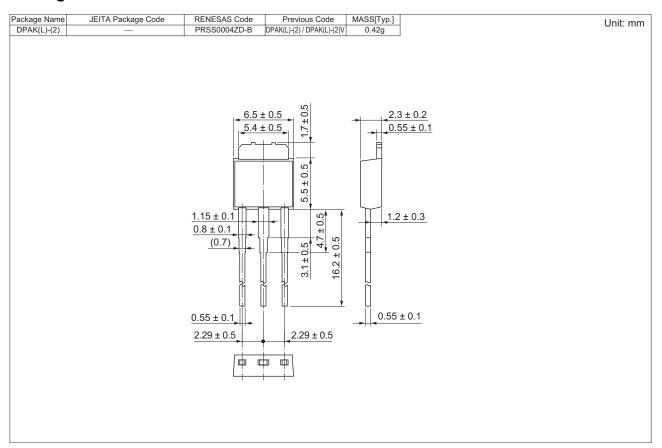


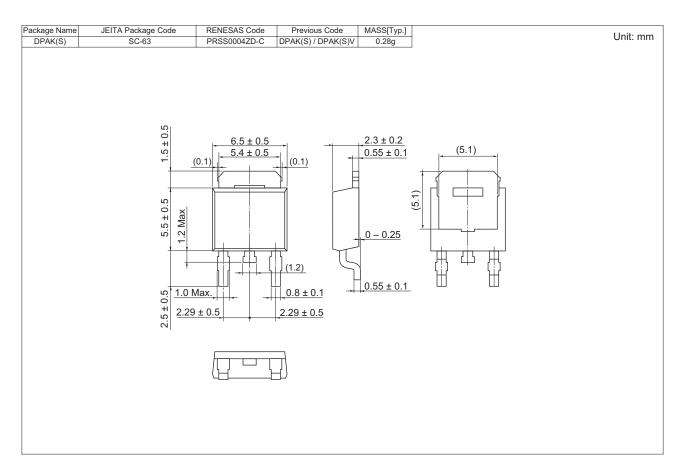






Package Dimensions





Ordering Information

Part Name	Quantity	Shipping Container
2SK3147L-E	3200 pcs	Box (Sack)
2SK3147STL-E	3000 pcs	Taping

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